

POWER MANAGEMENT

Description

The SC4216 is a high performance positive voltage regulator designed for use in applications requiring very low Input voltage and very low dropout voltage at up to 3 amperes. It operates with a V_{in} as low as 1.45V, with output voltage programmable as low as 0.5V. The SC4216 features ultra low dropout, ideal for applications where V_{out} is very close to V_{in} . Additionally, the SC4216 has an enable pin to further reduce power dissipation while shut down. The SC4216 provides excellent regulation over variations in line, load and temperature.

The SC4216 is available in an SOIC-8EDP (Exposed Die Pad) package. The output voltage can be set via an external divider or to fixed settings of 0.5V and 1.2V depending on how the FB pin is configured.

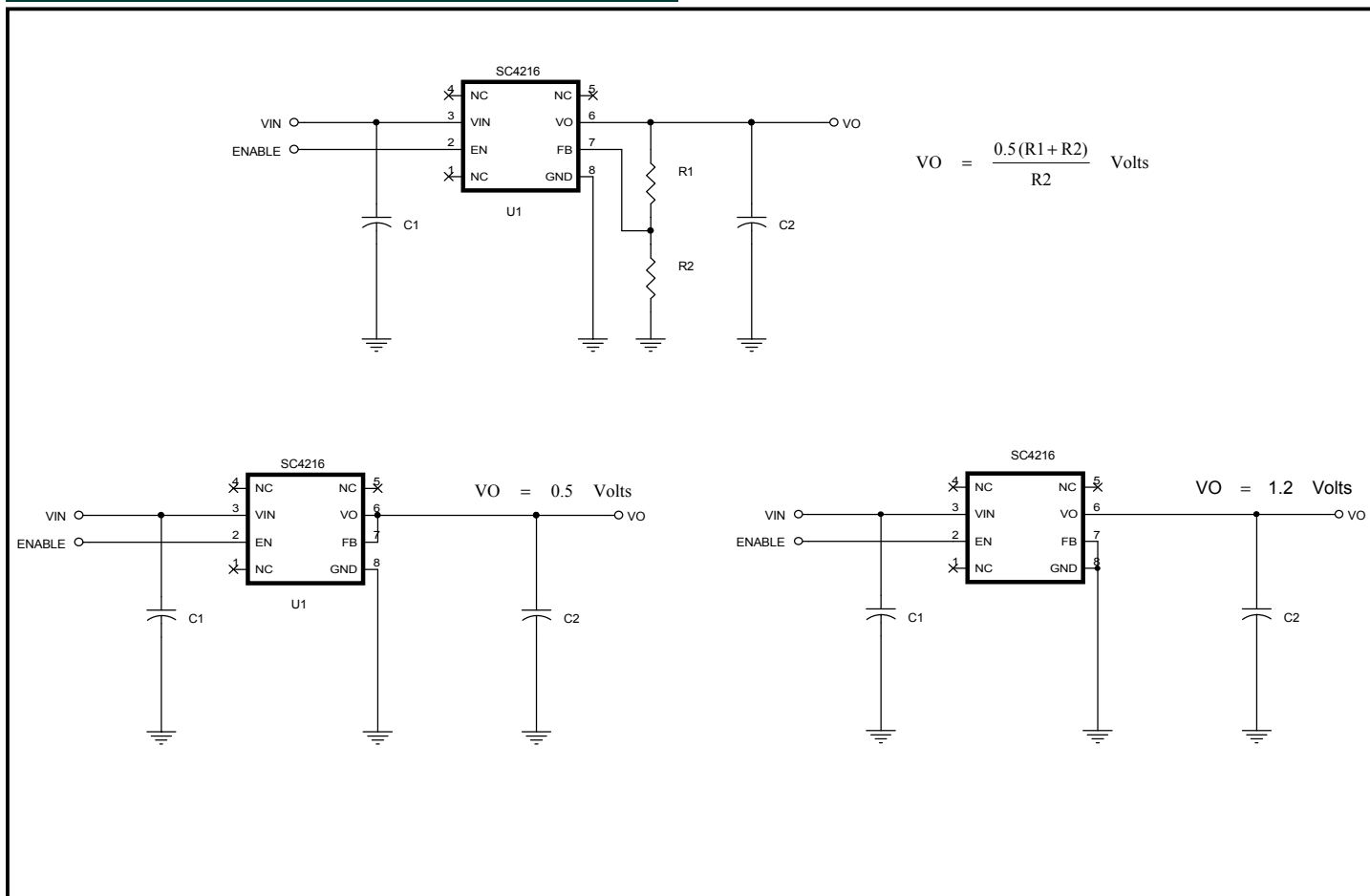
Features

- ◆ Input voltage as low as 1.45V
- ◆ 500mV dropout @ 3A
- ◆ Adjustable output from 0.5V
- ◆ Over current and over temperature protection
- ◆ Enable pin
- ◆ 10 μ A quiescent current in shutdown
- ◆ Full industrial temperature range
- ◆ Available in SOIC-8EDP Lead-free package. This product is fully WEEE and RoHS compliant

Applications

- ◆ Telecom/Networking cards
- ◆ Motherboards/Peripheral cards
- ◆ Industrial applications
- ◆ Wireless infrastructure
- ◆ Set top boxes
- ◆ Medical equipment
- ◆ Notebook computers
- ◆ Battery powered systems

Typical Application Circuits



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Absolute Maximum Ratings

Exceeding the specifications below may result in permanent damage to the device, or device malfunction. Operation outside of the parameters specified in the Electrical Characteristics section is not implied.

Parameter	Symbol	Max	Units
V _{IN} , EN, V _O , FB to GND		7	V
Power Dissipation	P _D	Internally Limited	W
Thermal Resistance Junction to Ambient SOIC-8EDP(1)	θJA	36	°C/W
Thermal Resistance Junction to Case SOIC-8EDP(1)	θJC	5.5	°C/W
Operating Ambient Temperature Range	T _A	-40 to +85	°C
Operating Junction Temperature Range	T _J	-40 to +125	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C
Lead Temperature (Soldering) 10 Sec.	T _{LEAD}	300	°C
ESD Rating (Human Body Model)	V _{ESD}	2	kV

Note: (1) 2 square inch of FR-4, double sided, 1 oz. minimum copper weight.

Electrical Characteristics

Unless specified: V_{EN} = V_{IN}, V_{FB} = V_O, V_{IN} = 1.45V to 5.5V, V_O = V_{IN} - 0.5V and I_O = 10μA to 3A.
Values in **bold** apply over the full operating temperature range.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
VIN						
Supply Voltage Range	V _{IN}		1.45		5.5	V
Quiescent Current	I _Q	V _{IN} = 3.3V, I _O = 0A			3	mA
		V _{IN} = 5.5V, V _{EN} = 0V		10	50	μA
VO						
Output Voltage ⁽¹⁾	V _O	V _{IN} = V _O + 0.5V, I _O = 10mA	-2%	V _O	+2%	V
(Fixed Voltage, V _{FB} = 0)		Full I _O and V _{IN} Range	-3%		+3%	
Line Regulation ⁽¹⁾	REG _(LINE)	I _O = 10mA		0.2	0.4	%/V
Load Regulation ⁽¹⁾	REG _(LOAD)	10mA ≤ I _O ≤ 3A, 1.6V ≤ V _{IN} ≤ 5.5V		0.25	1.0	%
Dropout Voltage ⁽¹⁾⁽²⁾	V _D	I _O = 500mA		75	150	mV
					200	
		I _O = 1A		150	250	mV
					300	
		I _O = 1.5A		250	350	mV
					400	

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Electrical Characteristics (Cont.)

Unless specified: $V_{EN} = V_{IN}$, $V_{FB} = V_O$, $V_{IN} = 1.45V$ to $5.5V$, $V_O = V_{IN} - 0.5V$ and $I_O = 10\mu A$ to $3A$.
Values in **bold** apply over the full operating temperature range.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
VO (Cont.)						
Dropout Voltage ⁽¹⁾⁽²⁾	V_D	$I_O = 2A$		300	400	mV
					500	
		$I_O = 2.5A$		350	450	mV
					600	
		$I_O = 3A$		450	550	mV
					700	
		$I_O = 3A, 1.6V \leq V_{IN} \leq 5.5V$		400	500	mV
					650	
Minimum Load Current ⁽³⁾	I_O	$V_{IN} = V_O + 0.5V$			10	μA
Current Limit	I_{CL}		3.5	4.5	5.0	A
Feedback						
Reference Voltage ⁽¹⁾	V_{REF}	$V_{IN} = 3.3V, V_{FB} = V_{OUT}, I_O = 10mA$	0.495	0.5	0.505	V
		Full I_{OUT} , and V_{IN} Range	0.490		0.510	
Feedback Pin Current ⁽⁴⁾	I_{ADJ}	$V_{FB} = V_{REF}$		80	200	nA
Feedback Pin Threshold ⁽⁵⁾	$V_{TH(FB)}$		0.05	0.16	0.40	V
EN						
Enable Pin Current	I_{EN}	$V_{EN} = 0V, V_{IN} = 3.3V$		1.5	10	μA
Enable Pin Threshold	V_{IH}	$V_{IN} = 3.3V$	1.6			V
	V_{IL}	$V_{IN} = 3.3V$			0.4	
Over Temperature Protection						
High Trip level	T_{HI}			160		$^{\circ}C$
Hysteresis	T_{HYST}			10		$^{\circ}C$

Notes:

- (1) Low duty cycle pulse testing with Kelvin connections required.
- (2) Defined as the input to output differential at which the output voltage drops to 1.5% below the value measured at a differential of 0.8V.
- (3) Required to maintain regulation. Voltage set resistors R1 and R2 are usually utilized to meet this requirement.
- (4) Guaranteed by design.
- (5) When V_{FB} exceeds this threshold, the "Sense Select" switch disconnects the internal feedback chain from the error amplifier and connects V_{FB} instead.

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Pin Configuration

Ordering Information

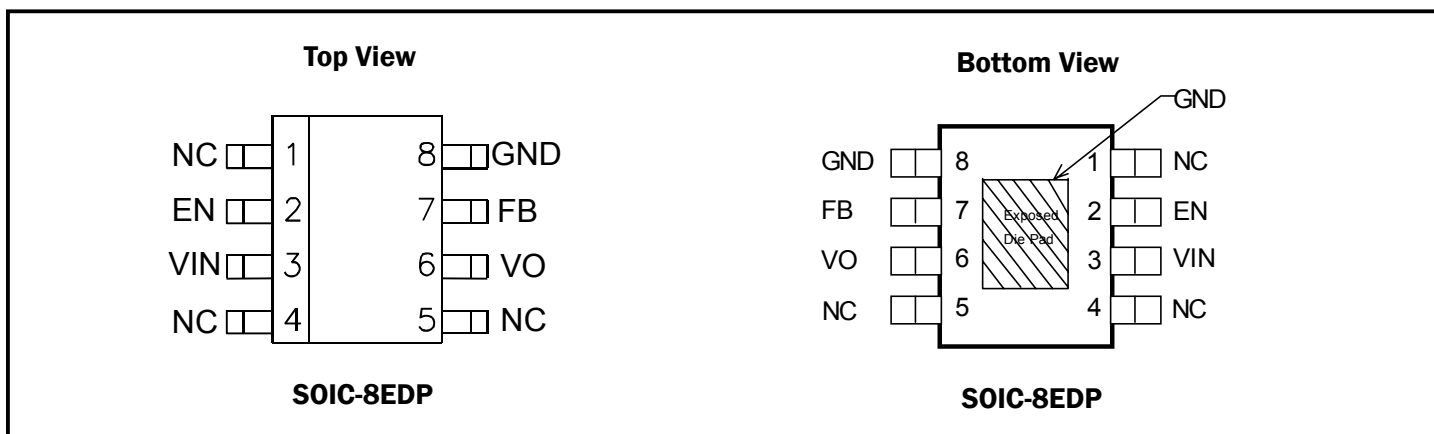
Part Number	Package	Temp. Range (T _j)
SC4216STRT ⁽¹⁾⁽²⁾	SOIC-8EDP	-40 to +125 °C
SC4216EVB	Evaluation Board	

Notes:

(1) Only available in tape and reel packaging. A reel contains 2500 devices for the SOIC-8EDP package.

(2) Lead-free product. This product is fully WEEE and RoHS compliant.

Pin Configuration

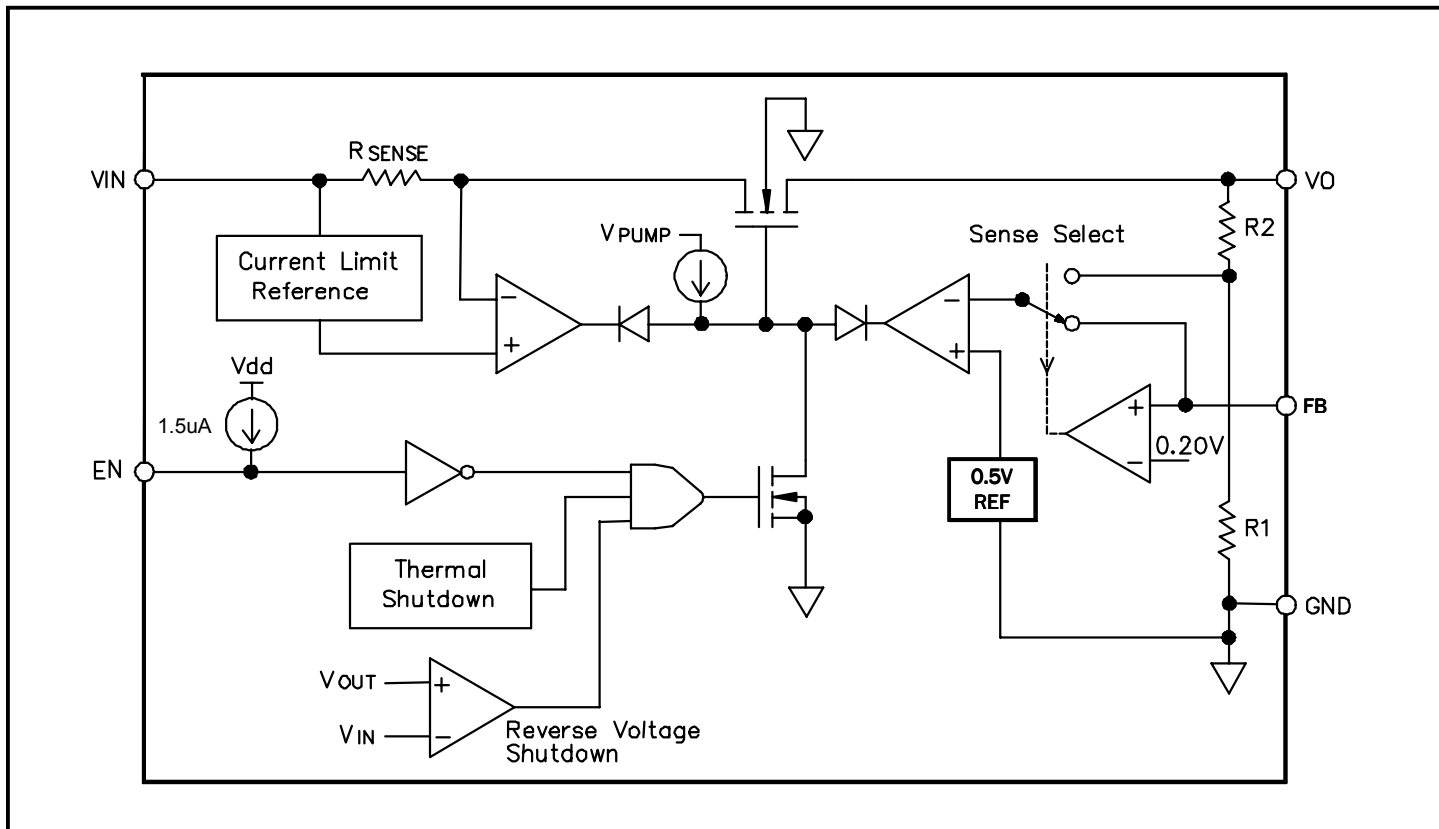


Pin Descriptions

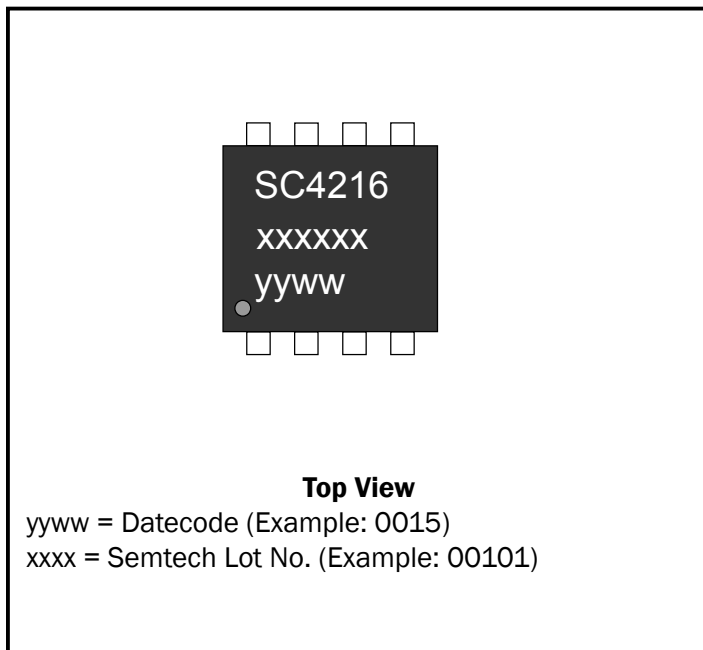
Pin #	Pin Name	Pin Description
2	EN	Enable Input. Pulling this pin below 0.4V turns the regulator off, reducing the quiescent current to a fraction of its operating value. The device will be enabled if this pin is left open. Connect to VIN if not being used.
3	VIN	Input voltage. For regulation at full load, the input to this pin must be between (VO+ 0.5V) and 5.5V. Minimum VIN = 1.45V. A large bulk capacitance should be placed closely to this pin to ensure that the input supply does not sag below 1.45V. Also a minimum of 4.7uF ceramic capacitor should be placed directly at this pin.
6	VO	The pin is the power output of the device. A minimum of 10uF capacitor should be placed directly at this pin.
7	FB	When this pin is grounded, an internal resistor divider sets the output voltage to 1.2V. If connected to the Vo pin, the output voltage will be set at 0.5V. If external feedback resistors are used, the output voltage will be (See Application Circuits on page 1): $VO = \frac{0.5 (R1 + R2)}{R2} \text{ Volts}$
8	GND	Reference ground.
1,4,5	NC	No Connection.
	THERMAL PAD	Pad for heatsinking purposes. Connect to ground plane using multiple vias. Not electrically connected internally.

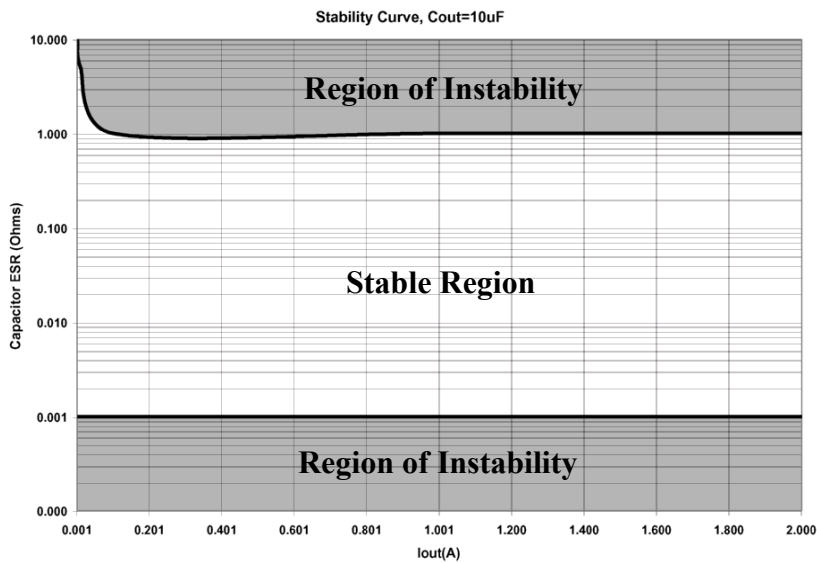
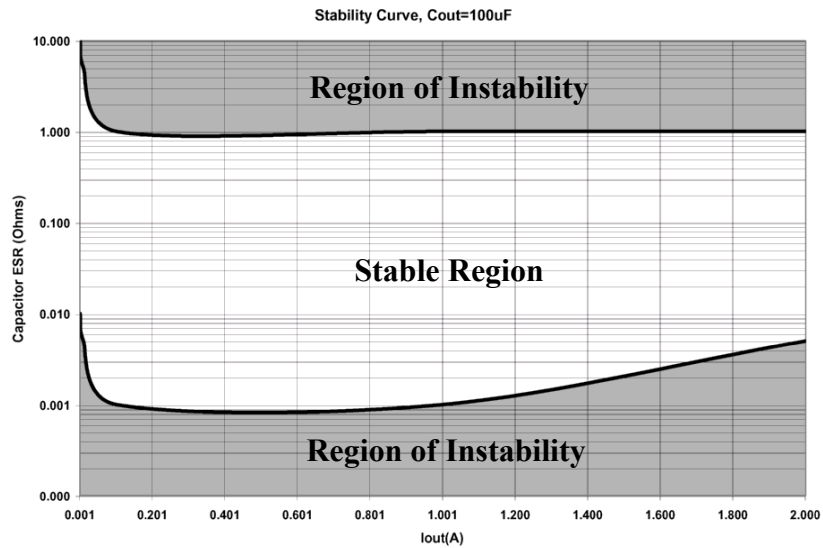
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Block Diagram



Marking Information



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Typical Characteristics


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Applications Information

Introduction

The SC4216 is intended for applications where high current capability and very low dropout voltage are required. It provides a very simple, low cost solution that uses very little pcb real estate. Additional features include an enable pin to allow for a very low power consumption standby mode, and a fully adjustable output.

Component Selection

Input capacitor: A large bulk capacitance $\geq 10\mu\text{F/A}$ (output load) should be closely placed to the input supply pin of the SC4216 to ensure that V_{IN} does not sag below 1.45V. Also a minimum of 4.7 μF ceramic capacitor is recommended to be placed directly next to the V_{IN} pin. This allows for the device being some distance from any bulk capacitance on the rail. Additionally, input droop due to load transients is reduced, improving load transient response. Additional capacitance may be added if required by the application.

Output capacitor: a minimum bulk capacitance of $\geq 10\mu\text{F/A}$ (output load), along with a 0.1 μF ceramic decoupling capacitor is recommended. Increasing the bulk capacitance will improve the overall transient response. The use of multiple lower value ceramic capacitors in parallel to achieve the desired bulk capacitance will not cause stability issues. Although designed for use with ceramic output capacitors, the SC4216 is extremely tolerant of output capacitor ESR values and thus will also work comfortably with tantalum output capacitors.

Noise immunity: in very electrically noisy environments, it is recommended that 0.1 μF ceramic capacitors be placed from IN to GND and OUT to GND as close to the device pins as possible.

Internal voltage selection: By connecting the FB pin to GND, an internal resistor divider will regulate the output voltage to 1.2V. If the FB pin is connected directly to the VO pin, the output voltage will be regulated to the 0.5V internal reference.

External voltage selection resistors: the use of 1% resistors, and designing for a current flow $\geq 10\mu\text{A}$ is recommended to ensure a well regulated output (thus $R2 \leq 50\text{k}\Omega$).

Enable: Pulling this pin below 0.4V turns the regulator off, reducing the quiescent current to a fraction of its operating value. A pull up resistor up to 400kOhms should be connected from this pin to the V_{IN} pin in application where supply voltages of $V_{\text{IN}} < 1.9\text{V}$ is required. For applications with higher voltages than 1.9V, EN pin could be left open or connected to V_{IN} .

Thermal Considerations

The power dissipation in the SC4216 is approximately equal to the product of the output current and the input to output voltage differential:

$$P_D \approx (V_{\text{IN}} - V_{\text{OUT}}) \cdot I_O$$

The absolute worst-case dissipation is given by:

$$P_{D(\text{MAX})} = (V_{\text{IN}(\text{MAX})} - V_{\text{OUT}(\text{MIN})}) \cdot I_{O(\text{MAX})} + V_{\text{IN}(\text{MAX})} \cdot I_{Q(\text{MAX})}$$

For a typical scenario, $V_{\text{IN}} = 3.3\text{V} \pm 5\%$, $V_{\text{OUT}} = 2.8\text{V}$ and $I_O = 1.5\text{A}$, therefore:

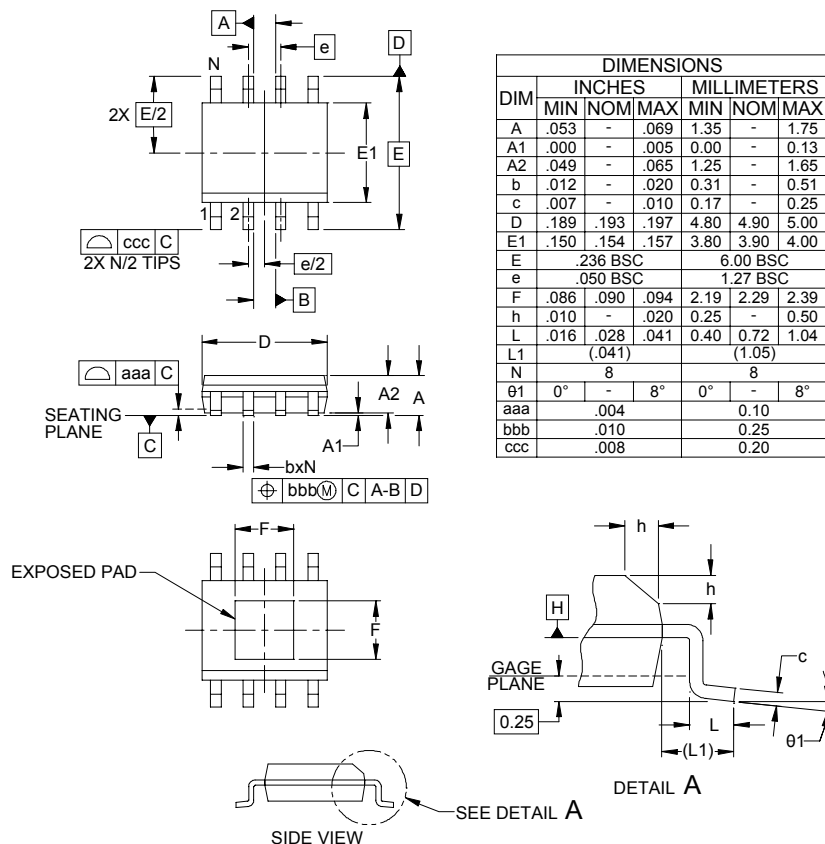
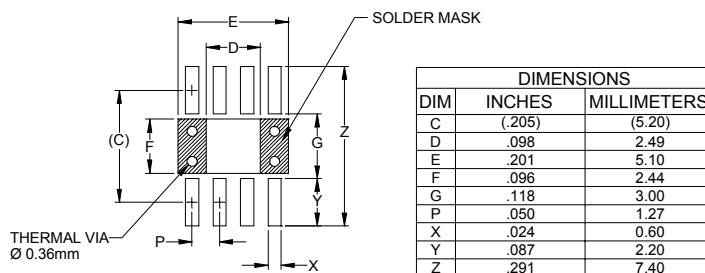
$$V_{\text{IN}(\text{MAX})} = 3.465\text{V}, V_{\text{OUT}(\text{MIN})} = 2.744\text{V} \text{ and } I_{Q(\text{MAX})} = 1.75\text{mA},$$

$$\text{Thus } P_{D(\text{MAX})} = 1.09\text{W}.$$

Using this figure, and assuming $T_{A(\text{MAX})} = 70^\circ\text{C}$, we can calculate the maximum thermal impedance allowable to maintain $T_J \leq 150^\circ\text{C}$:

$$R_{\text{TH}(J-A)(\text{MAX})} = \frac{(T_{J(\text{MAX})} - T_{A(\text{MAX})})}{P_{D(\text{MAX})}} = \frac{(150 - 70)}{1.09} = 73.4^\circ\text{C} / \text{W}$$

This should be achievable for the SOIC-8EDP package using pcb copper area to aid in conducting the heat away, such as one square inch of copper connected to the exposed die pad of the device. Internal ground/power planes and air flow will also assist in removing heat. For higher ambient temperatures it may be necessary to use additional copper area.

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Outline Drawing - SOIC-8EDP

Land Pattern - SOIC-8EDP


POWER MANAGEMENT**Contact Information**

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